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Kind regards,

Team Nexperia

PDTA113E series

PNP resistor-equipped transistors; R1 = 1 k Ω , R2 = 1 k Ω

Rev. 05 — 2 September 2009

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET).

Table 1. Product overview

Type number	Package	NPN		
	NXP	JEITA	JEDEC	complement
PDTA113EE	SOT416	SC-75	-	PDTC113EE
PDTA113EK	SOT346	SC-59A	TO-236	PDTC113EK
PDTA113EM	SOT883	SC-101	-	PDTC113EM
PDTA113ES[1]	SOT54 (TO-92)	SC-43A	TO-92	PDTC113ES
PDTA113ET	SOT23	-	TO-236AB	PDTC113ET
PDTA113EU	SOT323	SC-70	-	PDTC113EU

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2)

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- General purpose switching and amplification
- Inverter and interface circuits

Circuit drivers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I _O	output current (DC)		-	-	-100	mA
R1	bias resistor 1 (input)		0.7	1	1.3	$k\Omega$
R2/R1	bias resistor ratio		0.8	1	1.2	



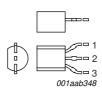
2. Pinning information

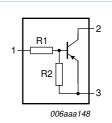
Table 3. Pinning

	3		
Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		R1 2
3	GND (emitter)	1 1 2 2 3 001aab347	1 R2 3
			006aaa148

S	O	П	5	4	Α

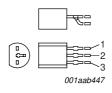
1	input (base)
2	output (collector)
3	GND (emitter)

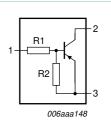




SOT54 variant

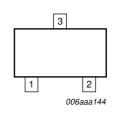
1	input (base)
2	output (collector)
3	GND (emitter)

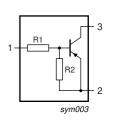




SOT23, SOT323, SOT346, SOT416

1	input (base)
2	GND (emitter)
3	output (collector)

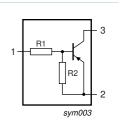




SOT883

1	input (base)
2	GND (emitter)
3	output (collector)





PDTA113E_SER_5

2 of 18

3. Ordering information

Table 4. Ordering information

Type number	Package				
	Name	Description	Version		
PDTA113EE	SC-75	plastic surface mounted package; 3 leads	SOT416		
PDTA113EK	SC-59A	plastic surface mounted package; 3 leads	SOT346		
PDTA113EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883		
PDTA113ES[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54		
PDTA113ET	-	plastic surface mounted package; 3 leads	SOT23		
PDTA113EU	SC-70	plastic surface mounted package; 3 leads	SOT323		

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5. Marking codes

indicate in the second	
Type number	Marking code ^[1]
PDTA113EE	16
PDTA113EK	17
PDTA113EM	G4
PDTA113ES	TA113E
PDTA113ET	*15
PDTA113EU	*14

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-50	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	-10	V
VI	input voltage				
	positive		-	+10	V
	negative		-	-10	V
Io	output current (DC)		-	-100	mA
I _{CM}	peak collector current		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT416		[1] -	150	mW
	SOT346		[1] -	250	mW
	SOT883		[2][3] _	250	mW
	SOT54		[1] -	500	mW
	SOT23		[1] -	250	mW
	SOT323		<u>[1]</u> -	200	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Refer to standard mounting conditions

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> -	-	833	K/W
	SOT346		<u>[1]</u> -	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> -	-	250	K/W
	SOT23		<u>[1]</u> -	-	500	K/W
	SOT323		<u>[1]</u> -	-	625	K/W

^[1] Refer to standard mounting conditions.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

^[2] Reflow soldering is the only recommended soldering method.

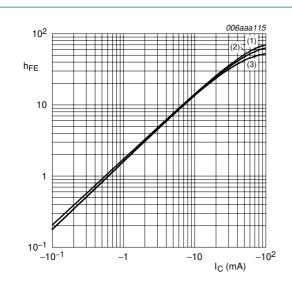
^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

7. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	–1	μΑ
	cut-off current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-4	mA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -40 \text{ mA}$	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -30 \text{ mA}; I_B = -1.5 \text{ mA}$	-	-	-150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-1.3	-0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = -300 \text{ mV}; I_{C} = -20 \text{ mA}$	-2	-1.7	-	V
R1	bias resistor 1 (input)		0.7	1	1.3	kΩ
R2/R1	bias resistor ratio		8.0	1	1.2	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	-	2	pF



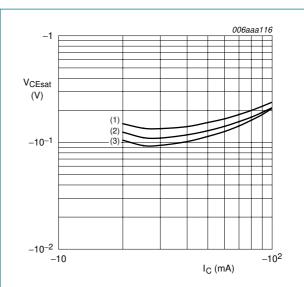
$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 1. DC current gain as a function of collector current; typical values



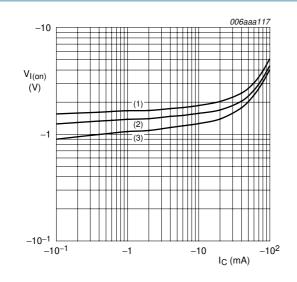
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



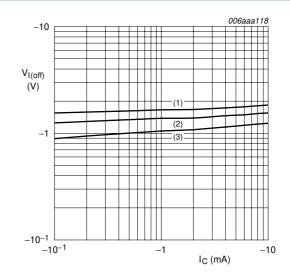


(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 3. On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 4. Off-state input voltage as a function of collector current; typical values

8. Package outline

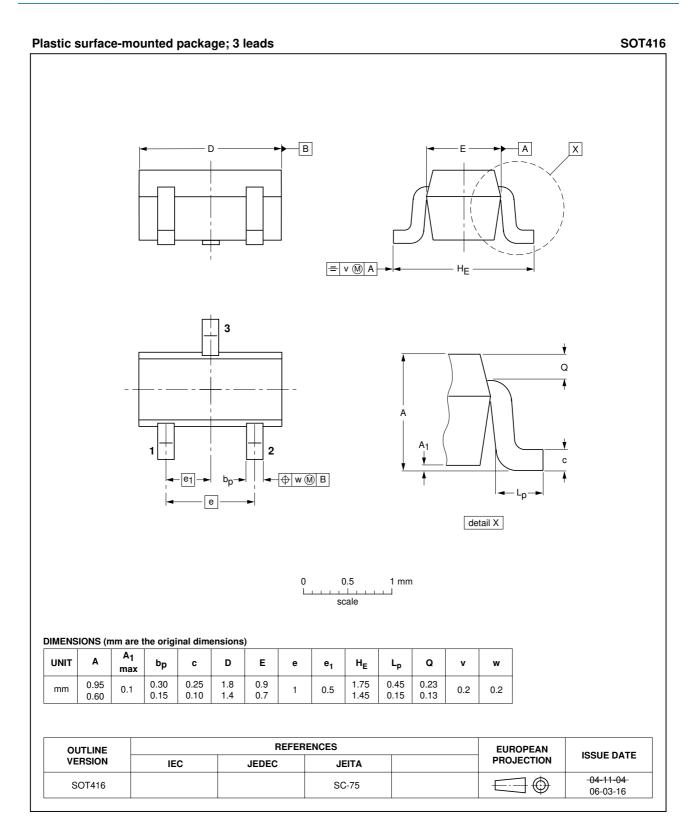


Fig 5. Package outline SOT416 (SC-75)

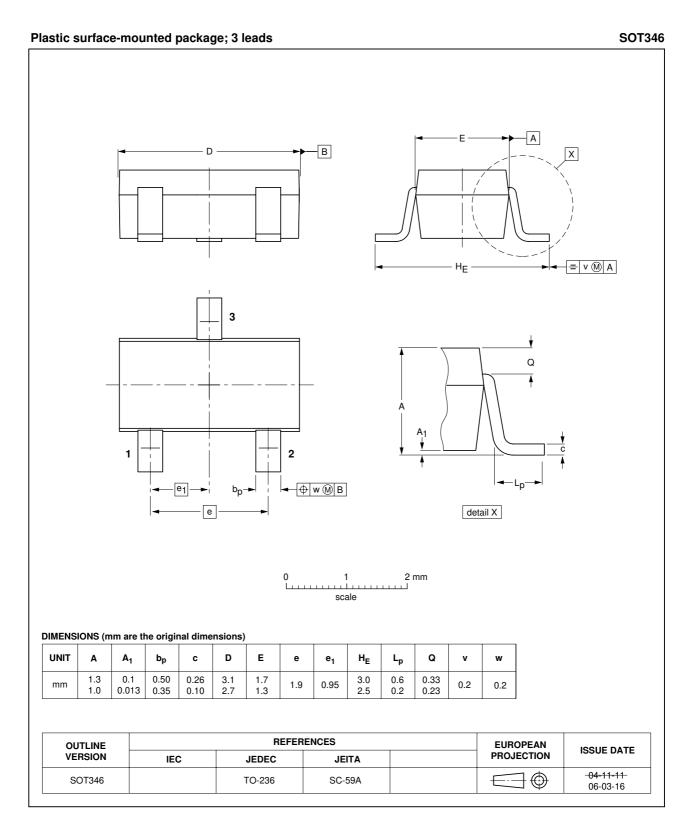


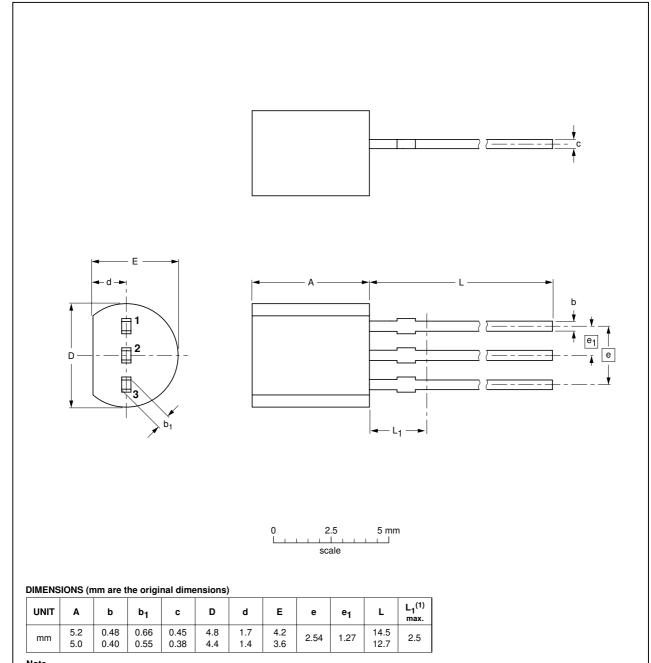
Fig 6. Package outline SOT346 (SC-59A/TO-236)

SOT883 Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm e₁ 0.5 I 1 mm **DIMENSIONS** (mm are the original dimensions) A₁ max. A⁽¹⁾ UNIT b b_1 D Ε e₁ L L_{1} 0.30 0.55 0.30 0.50 0.20 0.62 1.02 mm 0.03 0.35 0.65 0.47 0.46 0.12 0.55 0.22 0.22 1. Including plating thickness REFERENCES OUTLINE **EUROPEAN** ISSUE DATE VERSION **PROJECTION JEDEC** 03-02-05 \bigcirc SOT883 SC-101 03-04-03

Fig 7. Package outline SOT883 (SC-101)

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



Note

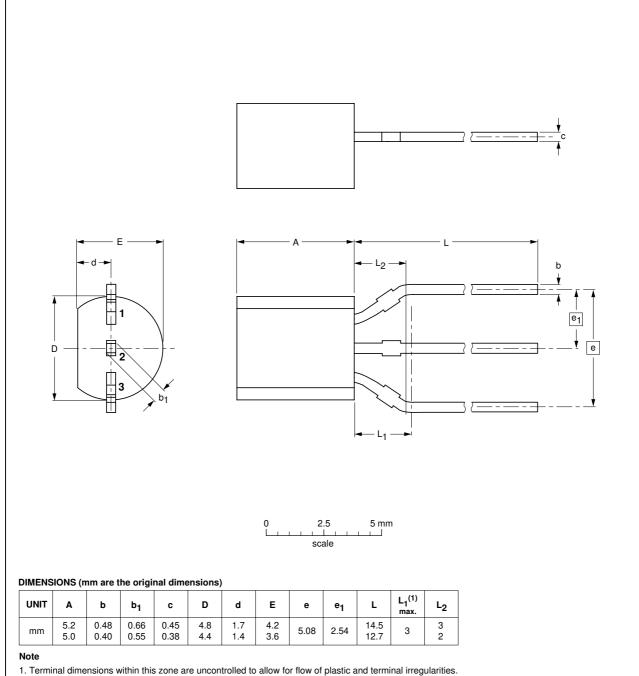
1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFERENCES EUROPEAN IS		EUROPEAN		ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			-04-06-28- 04-11-16

Fig 8. Package outline SOT54 (SC-43A/TO-92)

Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)

SOT54A

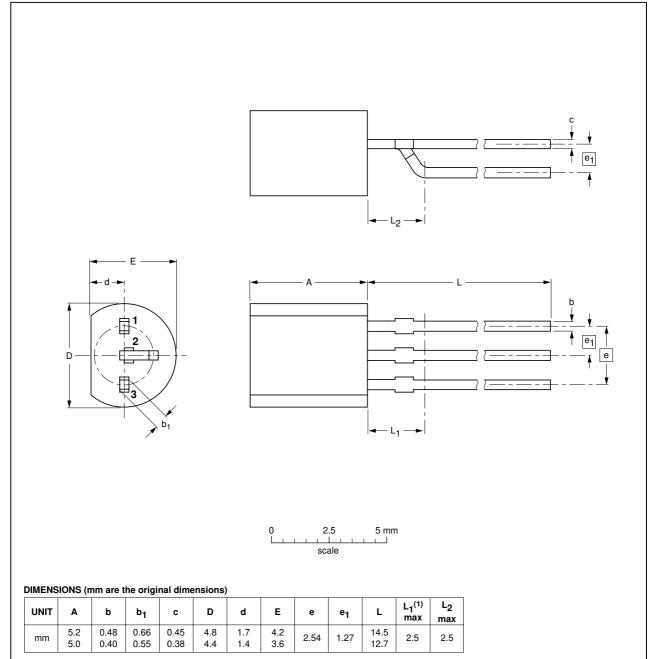


OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54A						97-05-13 04-06-28

Fig 9. Package outline SOT54A

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant



Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54 variant						-04-06-28 05-01-10

Fig 10. Package outline SOT54 variant

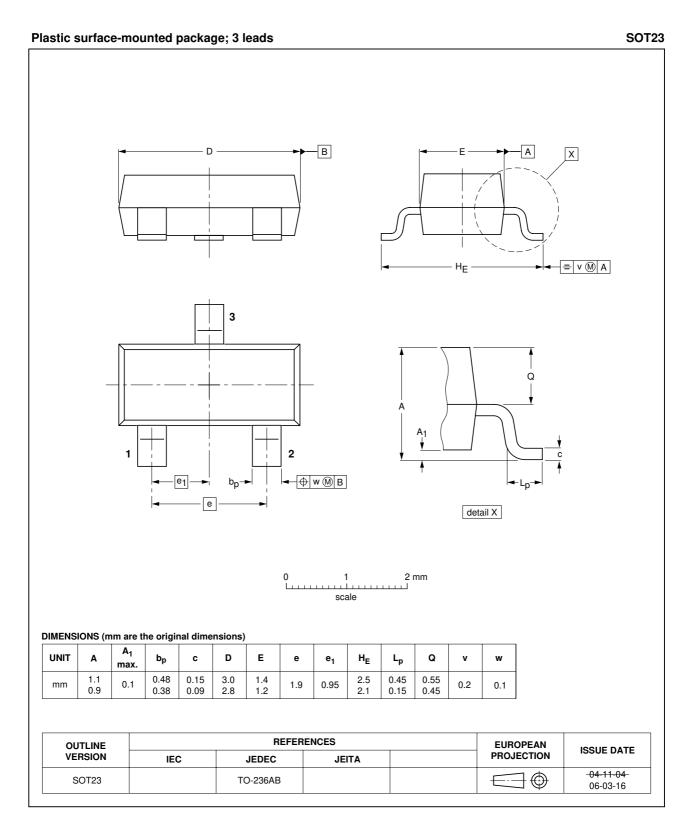


Fig 11. Package outline SOT23 (TO-236AB)

SOT323 Plastic surface-mounted package; 3 leads X = v M A H_{E} 2 **→** | w (M) B detail X 2 mm DIMENSIONS (mm are the original dimensions) Α1 ${\sf H}_{\sf E}$ UNIT D Ε Q bp С е Lp w e₁ 0.4 0.25 1.35 0.45 0.23 0.1 mm 1.3 0.65 0.2 0.2 0.8 0.3 1.15 REFERENCES OUTLINE **EUROPEAN ISSUE DATE** VERSION **PROJECTION** IEC JEDEC JEITA 04-11-04 06-03-16 SOT323 SC-70

Fig 12. Package outline SOT323 (SC-70)

9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing of	Packing quantity		
			3000	5000	10000	
PDTA113EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA113EK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA113EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTA113ES	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
	SOT54A	tape ammopack, wide patch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	
PDTA113ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTA113EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
Doddinon ID	i ioioaoo dato	Buta Cricci Status	Change notice	•
PDTA113E_SER_5	20090902	Product data sheet	-	PDTA113E_SER_4
Modifications:		eet was changed to reflect v legal definitions and discl		
	 Figure 5 "Pad 	ckage outline SOT416 (SC	<u>-75)"</u> updated	
	• Figure 6 "Page	ckage outline SOT346 (SC	-59A/TO-236)" updated	b
	 Figure 11 "Page 11" 	ackage outline SOT23 (TO	-236AB)" updated	
	 Figure 12 "Page 12" 	ackage outline SOT323 (So	<u>C-70)"</u> updated	
PDTA113E_SER_4	20050405	Product data sheet	-	PDTA113ET_3
PDTA113ET_3	20040720	Objective data sheet	-	PDTA113ET_2
PDTA113ET_2	20040415	Objective data sheet	-	PDTA113ET_1
PDTA113ET_1	20040316	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PDTA113E series

PNP resistor-equipped transistors; R1 = 1 k Ω , R2 = 1 k Ω

13. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications
1.4	Quick reference data
2	Pinning information 2
3	Ordering information
4	Marking 3
5	Limiting values 4
6	Thermal characteristics 4
7	Characteristics 5
8	Package outline 7
9	Packing information 15
10	Revision history 16
11	Legal information
11.1	Data sheet status 17
11.2	Definitions
11.3	Disclaimers
11.4	Trademarks
12	Contact information 17
13	Contents

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